

MT2201 - SD 3.0-SDR104 compliant integrated auto-direction control memory card voltage level translator with EMI filter and ESD protection

1. General description

The module is designed based on NVT4857UK produced by NXP Semiconductors (<https://www.nxp.com/docs/en/data-sheet/NVT4857UK.pdf>). It is an SD 3.0-compliant bidirectional dual voltage level translator with auto-direction control. It is designed to interface between a memory card operating at 1.8 V or 3.0 V signal levels and a host with a nominal supply voltage of 1.2 V to 1.8 V. The device supports SD 3.0 SDR104, SDR50, DDR50, SDR25, SDR12 and SD 2.0 High-Speed (50 MHz) and Default-Speed (25 MHz) modes. The device has an integrated voltage selectable low dropout regulator to supply the card-side I/Os, an auto-enable/ disable function connected to the VSD supply pin, built-in EMI filters and robust ESD protections (IEC 61000-4-2, level 4).

As shown in Fig. 1, the MT2201 converts the small BGA package NVT4857UK from 0.4 mm BGA to 1 mm pin pitch package to ease the PCB design and reduce the cost.

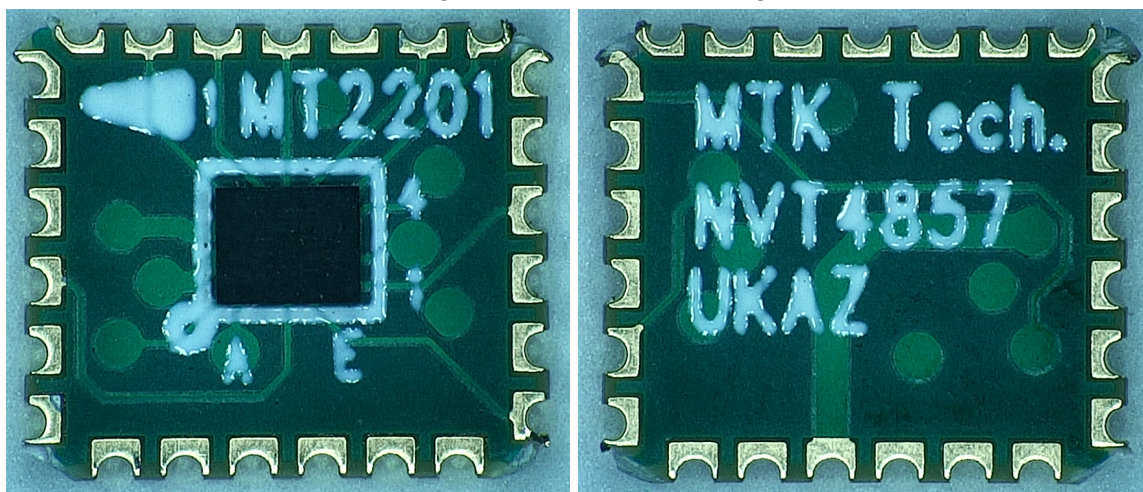


Fig.1 Top View (Left side) and Bottom View (Right side)

2. Features and benefits

- Supports up to 208 MHz clock rate
- SD 3.0 specification-compliant voltage translation to support SDR104, SDR50, DDR50, SDR25, SDR12, High-Speed and Default-Speed modes
- 1.2 V to 1.8 V host side interface voltage support
- Feedback channel for clock synchronization

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- e. 100 mA Low dropout voltage regulator to supply the card-side I/Os
 - f. Low power consumption by push-pull output stage with break-before-make architecture
 - g. Automatic enable and disable through VSD
 - h. Integrated pull-up and pull-down resistors: no external resistors required
 - i. Integrated EMI filters suppress higher harmonics of digital I/Os
 - j. Integrated 8 kV ESD protection according to IEC 61000-4-2, level 4 on card side
 - k. Level shifting buffers keep ESD stress away from the host (zero-clamping concept)
 - l. 25 pins four side; pitch 1 mm package

3. Applications

- a. Xilinx FPGA such as ZYNQ US+/Versal
- b. Altera FPGA SoC
- c. Other large size SD card interface

4. Schematics

All 20 pins of NVT4857UK have been connected to MT2201 pins as shown in the Fig. 2.

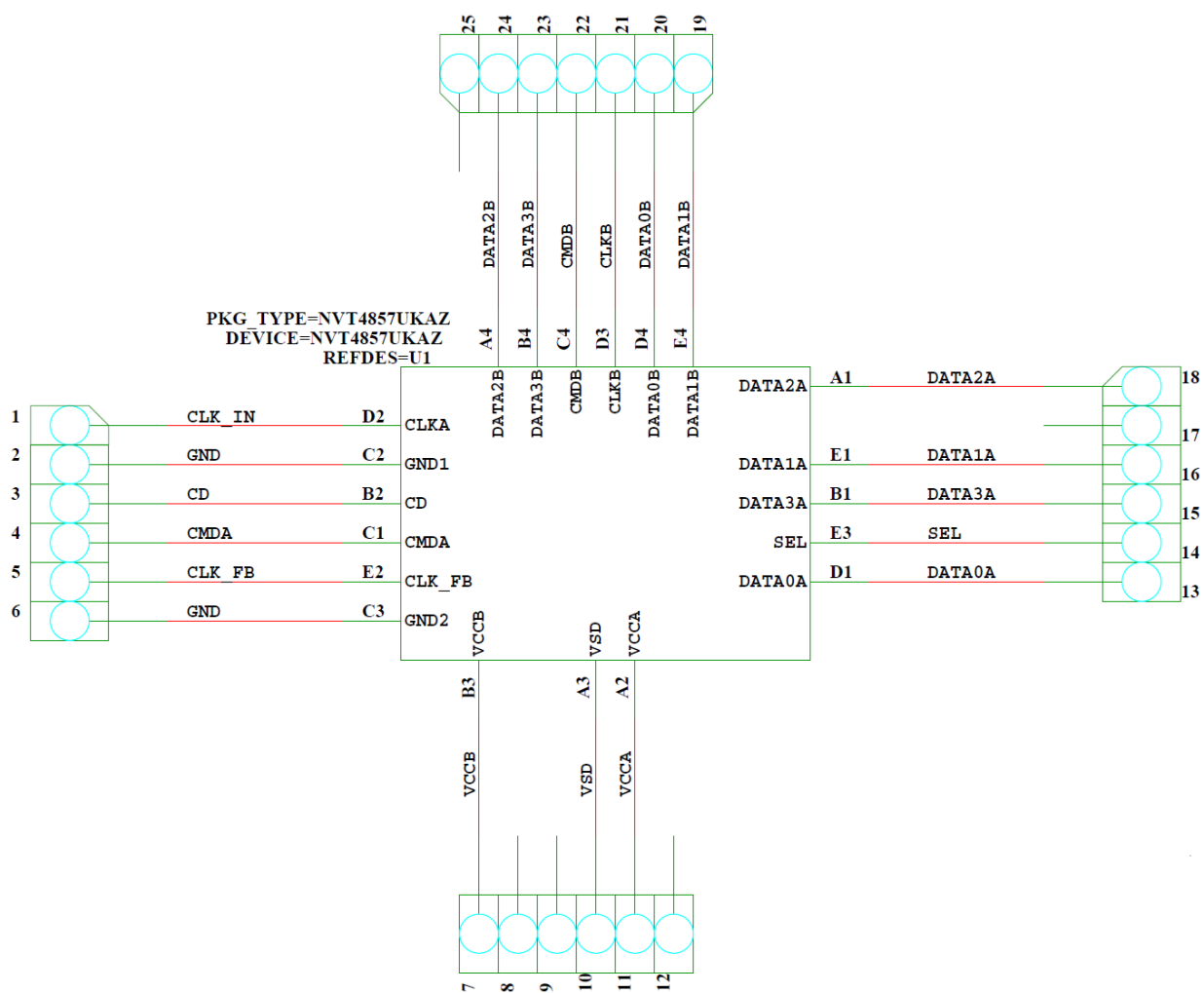


Fig. 2 MT2201 schematics

5. Pinning information

Table 1. Pin mapping and description

Pin Number	Pin Name	Type	Description
1	CLK_IN	Input	clock signal input on host side
2	GND	Power	power supply ground
3	CD	Output	card detect switch biasing output
4	CMDA	Input/Output	command input or output on host side
5	CLK_FB	Output	clock feedback output on host side

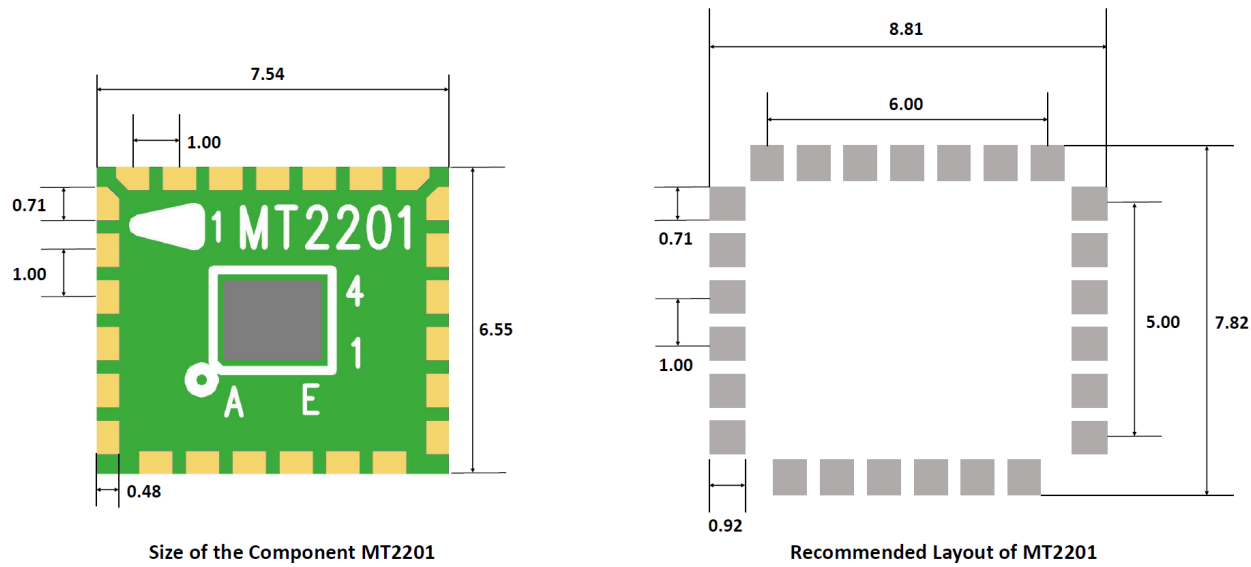
6	GND	Power	power supply ground
7	VCCB	Power	internal supply decoupling (VLDO)
8	NC	NC	Not Connected
9	NC	NC	Not Connected
10	VSD	Power	supply voltage
11	VCCA	Power	supply voltage from host side
12	NC	NC	Not Connected
13	DATA0A	Input/Output	data 0 input or output on host side
14	SEL	Input	card side I/O voltage level select
15	DATA3A	Input/Output	data 3 input or output on host side
16	DATA1A	Input/Output	data 1 input or output on host side
17	NC	NC	Not Connected
18	DATA2A	Input/Output	data 2 input or output on host side
19	DATA1B	Input/Output	data 1 input or output on memory card side
20	DATA0B	Input/Output	data 0 input or output on memory card side
21	CLKB	Output	clock signal output on memory card side
22	CMDB	Input/Output	command input or output on memory card side
23	DATA3B	Input/Output	data 3 input or output on memory card side
24	DATA2B	Input/Output	data 2 input or output on memory card side
25	NC	NC	Not Connected

6. Functional description

Please refer to NVT4857UK Data Sheet for the details.

<https://www.nxp.com/docs/en/data-sheet/NVT4857UK.pdf>

7. Packing information



Note: All labels in this figure are in millimeters